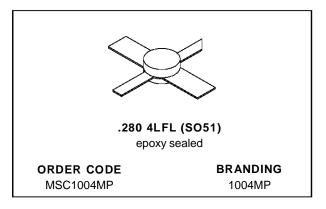


MSC1004MP

RF & MICROWAVE TRANSISTORS AVIONICS APPLICATIONS

- 1025 1150 MHz
- RUGGEDIZED VSWR ∞:1
- INTERNAL INPUT MATCHING
- LOW THERMAL RESISTANCE
- Pout = 4.0 W MIN. WITH 9.0 dB GAIN

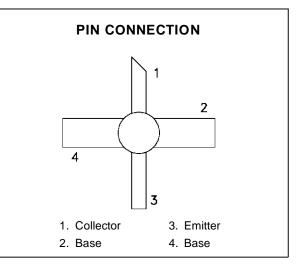


DESCRIPTION

The MSC1004MP is a low-level Class C pulsed transistor specifically designed for DME/IFF driver or output applications.

These devices are capable of withstanding a ∞ :1 load VSWR at any phase angle under full rated conditions. Low RF thermal resistance and automatic bonding techniques ensure high reliability and product consistency.

The MSC1004MP is housed in the IMPAC[™] package with internal input matching.



ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit	
P _{DISS}	Power Dissipation [*] $(T_C \le 100^{\circ}C)$	18	W	
Ι _C	Device Current*	650	mA	
Vcc	Collector-Supply Voltage*	32	V	
TJ	Junction Temperature	200	°C	
Тѕтс	Storage Temperature	– 65 to +150	°C	

THERMAL DATA

R _{TH(j-c)}	Junction-Case Thermal Resistance*	5	°C/W		
*Analise substantial DE source liference and an					

*Applies only to rated RF amplifier operation

ELECTRICAL SPECIFICATIONS ($T_{case} = 25^{\circ}C$)

STATIC

Symbol	Test Conditions	Value			Unit		
	Test conditions		Min.	Тур.	Max.		
ВVсво	I _C = 1 mA	$I_E = 0 \text{ mA}$		45		_	V
BV _{CER}	I _C = 5 mA	$R_{BE} = 10 \ \Omega$		45			V
BV _{EBO}	I _E = 1 mA	Ic = 0mA		3.5	_		V
ICES	V _{CE} = 28 V					1.0	mA
hFE	$V_{CE} = 5 V$	I _C = 200 mA		30		300	_

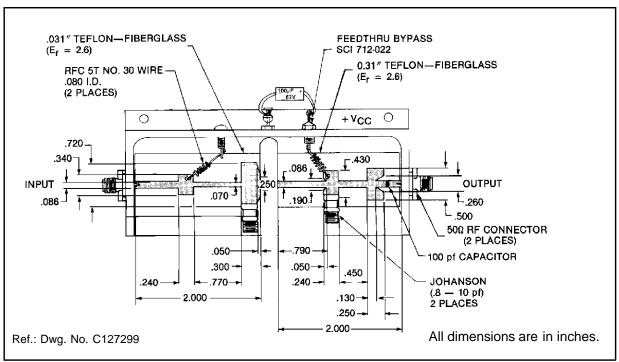
DYNAMIC

Symbol	Test Conditions		Value			Unit	
Symbol			Min.	Тур.	Max.	Unit	
Pout	f = 1025 – 1150 MHz	$P_{\text{IN}}=500\ mW$	$V_{CC}=28\ V$	4.0		_	W
ης	f = 1025 – 1150 MHz	$P_{\text{IN}} = 500 \text{ mW}$	$V_{CC}=28\ V$	35		—	%
GP	f = 1025 – 1150 MHz	$P_{IN} = 500 \text{ mW}$	$V_{CC} = 28 V$	9.0		—	dB

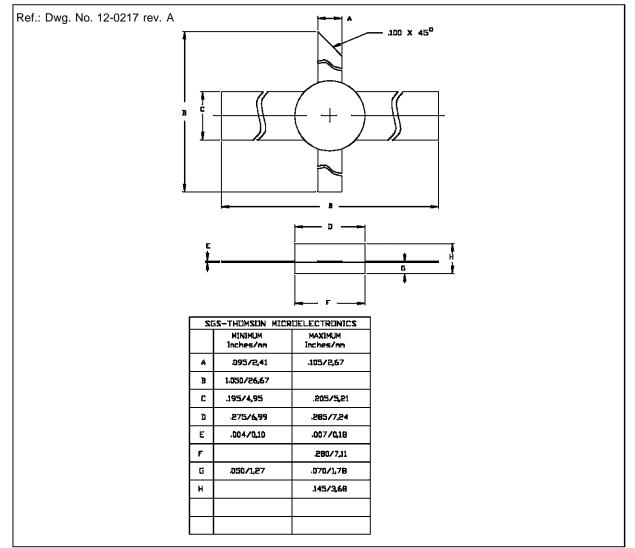
Note: Pulse Width = 10μ Sec

Duty Cycle = 1%

TEST CIRCUIT



PACKAGE MECHANICAL DATA



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